

الامتحان ورقة

ANSWER ALL QUESTIONS

Question One:

1- Determine V_o for the circuits shown in Fig.1.

(20 Marks)

Question Two:

2- Determine the range of values of V_i that will maintain the zener diode in Fig.2 in the ON state.

(15 Marks)

Question three:

3- Prove that the voltage divider bias of BJT is the best one, using the current stability factor

(10 Marks)

Question Four

4- Design a BJT voltage divider bias amplifier if $V_{cc}=10v$, $R_E=1k\Omega$, $R_2=20k\Omega$, $I_C=2mA$, $V_{CE}=10v$.

(15 Marks)

Question Five

5-a- Draw and Explain the n-channel enhancement MOSFET

(10 Marks)

5-b-Explain How CMOS can be used as inverter.

(10 Marks)

Question Six

6- Determine V_D , V_C for the circuit shown in Fig.3.

(20 Marks)

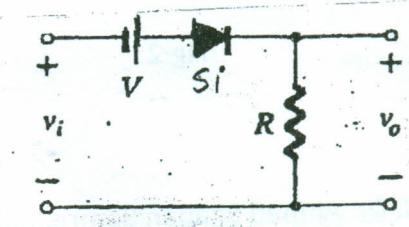
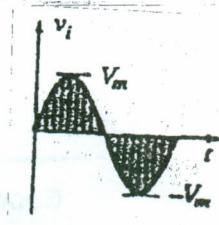
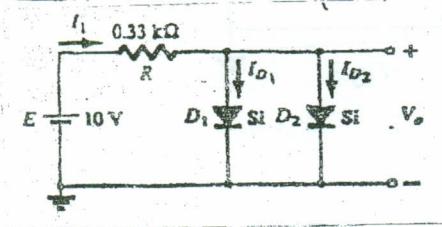


Fig.1

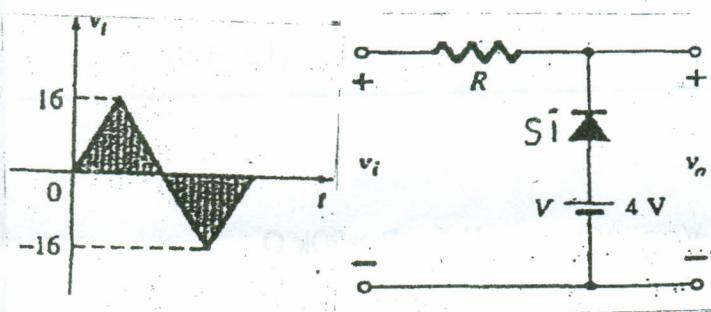
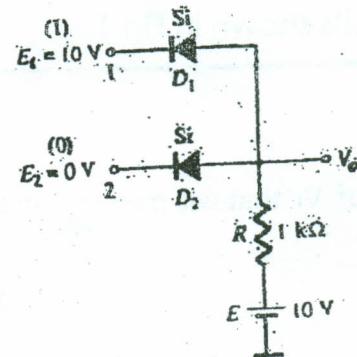
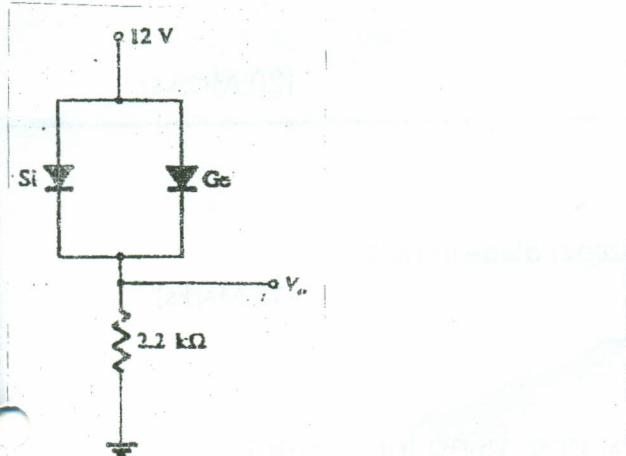
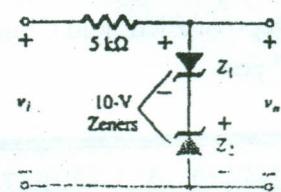
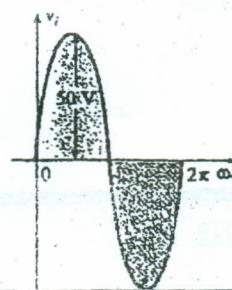
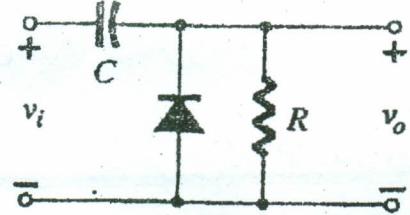
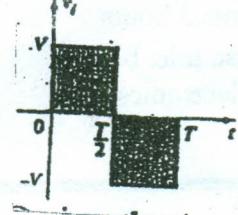


Fig.1

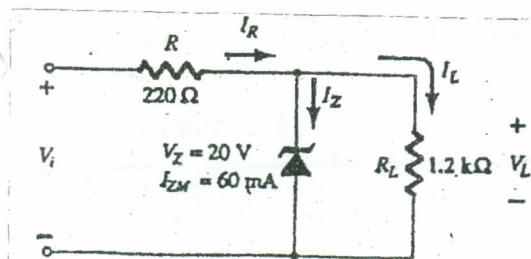


Fig.2

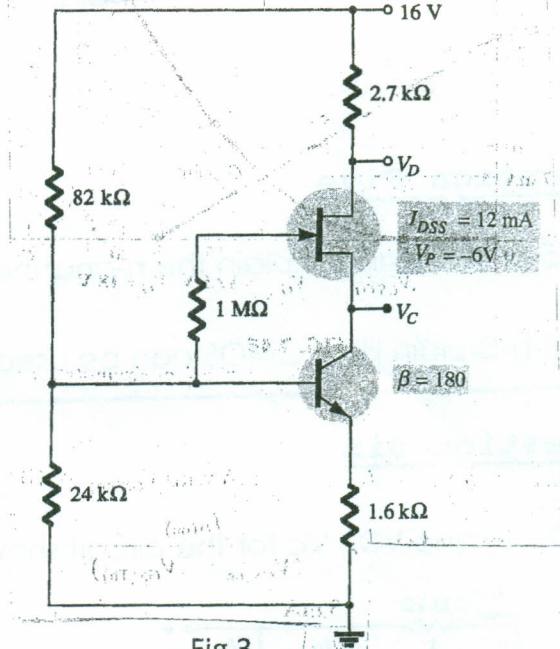


Fig.3

Good luck

Prof. Dr. Ahmed Shaban Samra.....